1. General description

PNP/PNP high power double bipolar transistor in a SOT1205 (LFPAK56D) Surface-Mounted Device (SMD) power plastic package.

NPN/NPN complement: PHPT610030NK-Q

NPN/PNP complement: PHPT610030NPK

2. Features and benefits

- High thermal power dissipation capability
- Suitable for high temperature applications up to 175 °C
- Reduced Printed-Circuit Board (PCB) requirements comparing to transistors in DPAK
- · High energy efficiency due to less heat generation
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- Motor control
- · Power management
- · Load switch
- · Linear mode voltage regulator
- Backlighting applications
- Relay replacement

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transistor	•			'		'
V _{CEO}	collector-emitter voltage	open base	-	-	-100	V
Ic	collector current		-	-	-3	Α
R _{CEsat}	collector-emitter saturation resistance	I_C = -2 A; I_B = -0.2 A; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	110	180	mΩ



5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1	8 7 6 5	
2	B1	base TR1	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	C1 B2 E2
3	E2	emitter TR2		
4	B2	base TR2		TR2
5	C2	collector TR2		TRI
6	C2	collector TR2		E1 B1 C2
7	C1	collector TR1		sym138
8	C1	collector TR1	LFPAK56D; Dual LFPAK (SOT1205)	Sylliso

6. Ordering information

Table 3. Ordering information

Type number	Package						
	Name	Description	Version				
PHPT610030PK-Q	LFPAK56D; Dual LFPAK	plastic, single ended surface mounted package (LFPAK56D); 8 leads	SOT1205				

7. Marking

Table 4. Marking codes

Type number	Marking code
PHPT610030PK-Q	10030PK

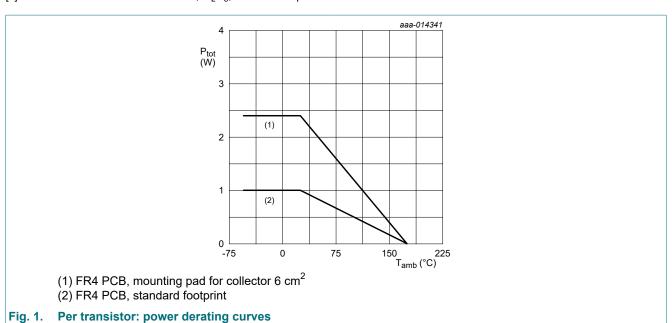
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or			<u> </u>	'	
V _{CBO}	collector-base voltage	open emitter		-	-100	V
V _{CEO}	collector-emitter voltage	open base		-	-100	V
V _{EBO}	emitter-base voltage	open collector		-	-8	V
I _C	collector current			-	-3	Α
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-8	Α
I _B	base current			-	-0.5	Α
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	1	W
			[2]	-	2.4	W
			[3]	-	25	W
Per device	<u> </u>		,	'	'	
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	1.25	W
			[2]	-	3	W
			[4]	-	5	W
T _j	junction temperature			-	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².
- [3] Power dissipation from junction to mounting base.
- [4] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.



9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transis	tor		,				_
R _{th(j-a)}	thermal resistance from	in free air	[1]	-	-	150	K/W
	junction to ambient		[2]	-	-	62.5	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	6	K/W
Per device					1		_
R _{th(j-a)}	thermal resistance from	in free air	[1]	-	-	120	K/W
	junction to ambient		[2]	-	-	50	K/W
			[3]	-	-	30	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².
- [3] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.

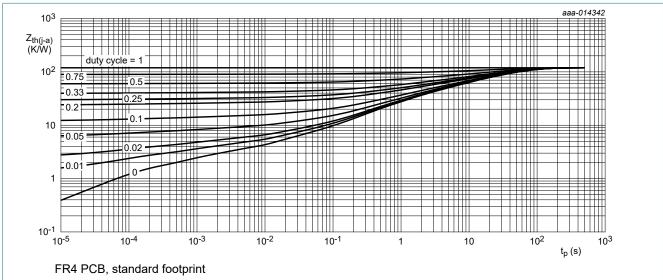


Fig. 2. Per transistor: transient thermal impedance from junction to ambient as a function of pulse duration; typical values

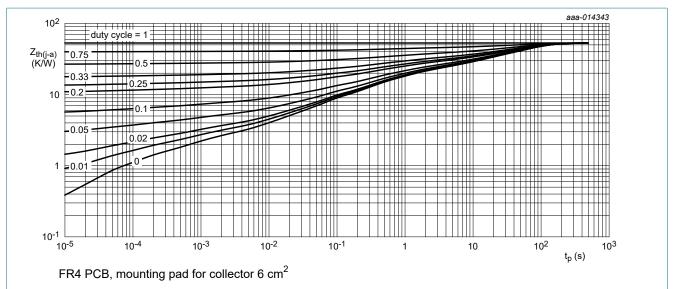
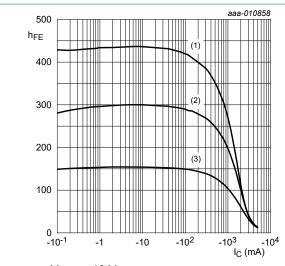


Fig. 3. Per transistor: transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transist	tor			_		
I _{CBO}	collector-base cut-off	V _{CB} = -80 V; I _E = 0 A; T _{amb} = 25 °C	-	-	-100	nA
	current	V _{CB} = -80 V; I _E = 0 A; T _j = 150 °C	-	-	-50	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = -7 V; I _C = 0 A; T _{amb} = 25 °C	-	-	-100	nA
I _{CES}	collector-emitter cut-off current	V _{CE} = -80 V; V _{BE} = 0 V; T _{amb} = 25 °C	-	-	-100	nA
h _{FE}	DC current gain	V _{CE} = -10 V; I _C = -500 mA; T _{amb} = 25 °C	150	220	-	
		V_{CE} = -10 V; I_{C} = -1 A; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	80	210	-	
		V_{CE} = -10 V; I_{C} = -2 A; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	20	100	-	
		V_{CE} = -10 V; I_{C} = -3 A; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	10	40	-	
OLSat	collector-emitter	I _C = -500 mA; I _B = -50 mA; T _{amb} = 25 °C	-	-70	-110	mV
	saturation voltage	I_C = -2 A; I_B = -200 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-220	-360	mV
R _{CEsat}	collector-emitter saturation resistance	I_C = -2 A; I_B = -0.2 A; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	110	180	mΩ
V _{BEsat}	base-emitter saturation voltage	I_C = -1 A; I_B = -50 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-0.91	-1	V
		I_C = -2 A; I_B = -200 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-1.02	-1.2	V
V_{BEon}	base-emitter turn-on voltage	V_{CE} = -2 V; I_{C} = -100 mA; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-0.68	-0.9	V
t _d	delay time	V _{CC} = -12.5 V; I _C = -1 A; I _{Bon} = -50 mA;	-	20	-	ns
r	rise time	I _{Boff} = 50 mA; T _{amb} = 25 °C	-	180	-	ns
ton	turn-on time		-	200	-	ns
ts	storage time		-	350	-	ns
t _f	fall time		-	220	-	ns
off	turn-off time		-	570	-	ns
f _T	transition frequency	V_{CE} = -10 V; I_{C} = -100 mA; f = 100 MHz; T_{amb} = 25 °C	-	125	-	MHz
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A};$ f = 1 MHz; $T_{amb} = 25 \text{ °C}$	-	30	-	pF

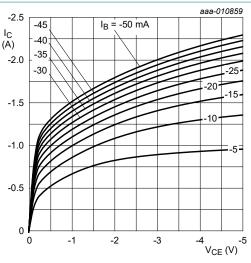


$$V_{CE} = -10 \text{ V}$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

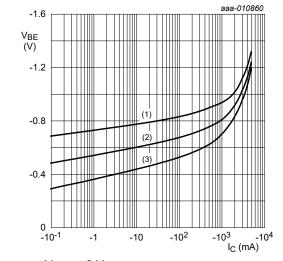
$$(3) T_{amb} = -55 °C$$

Fig. 4. DC current gain as a function of collector current; typical values



T_{amb} = 25 °C

Fig. 5. Collector current as a function of collectoremitter voltage; typical values



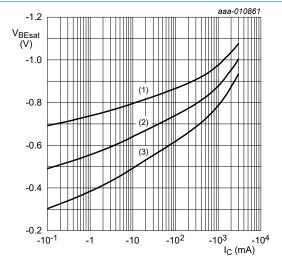
$$V_{CE} = -2 V$$

$$(1) T_{amb} = -55 °C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) T_{amb} = 100 °C

Fig. 6. Base-emitter voltage as a function of collector current; typical values



$$I_C/I_B = 20$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 7. Base-emitter saturation voltage as a function of collector current; typical values

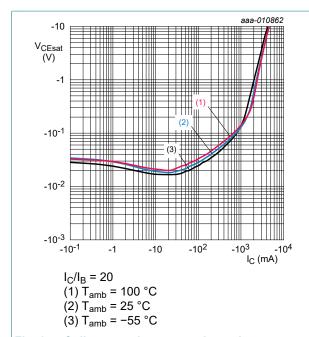


Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values

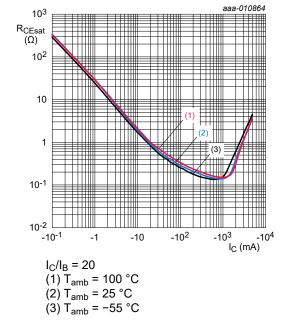


Fig. 10. Collector-emitter saturation resistance as a function of collector current; typical values

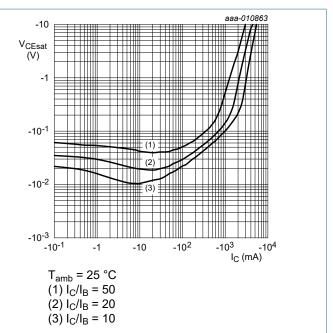


Fig. 9. Collector-emitter saturation voltage as a function of collector current; typical values

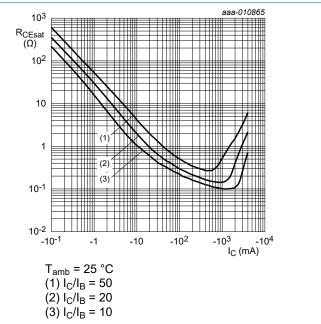
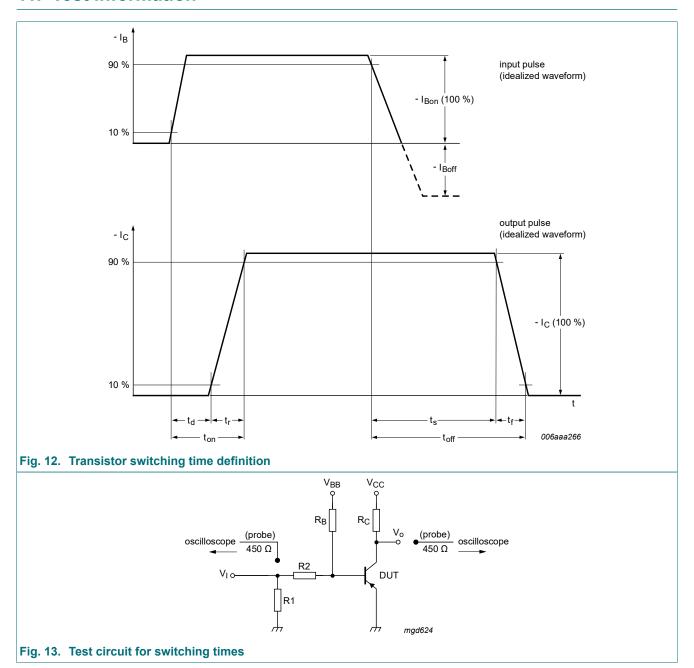


Fig. 11. Collector-emitter saturation resistance as a function of collector current; typical values

11. Test information



Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline

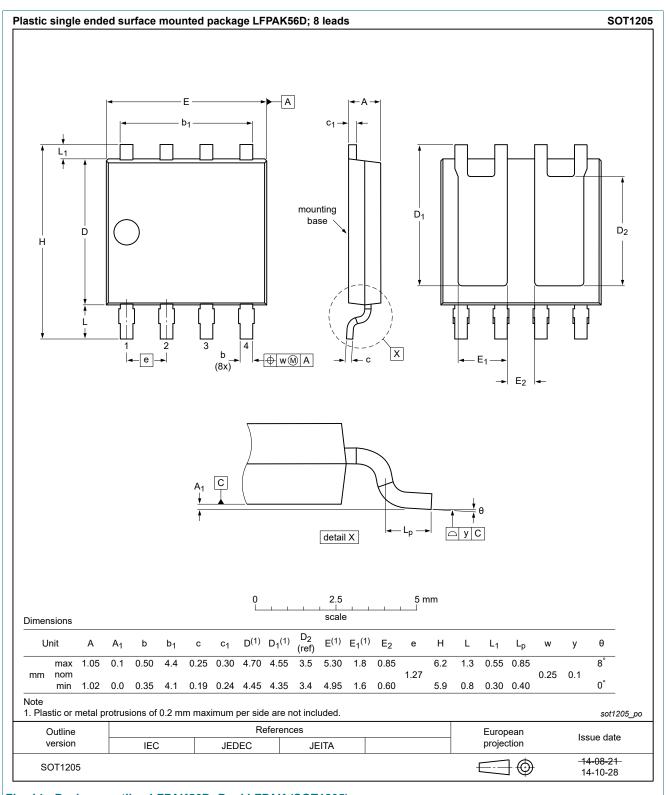


Fig. 14. Package outline LFPAK56D; Dual LFPAK (SOT1205)

13. Soldering

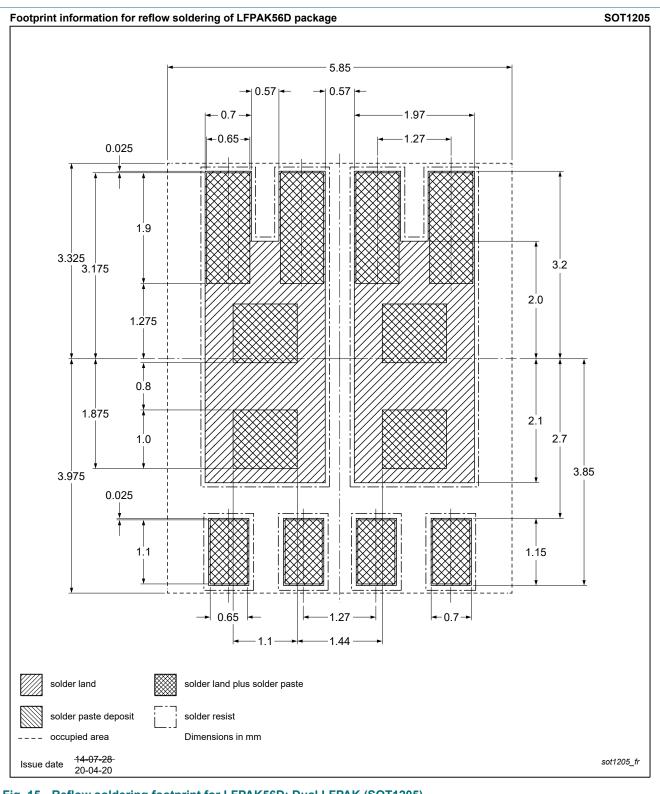


Fig. 15. Reflow soldering footprint for LFPAK56D; Dual LFPAK (SOT1205)

14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PHPT610030PK-Q v.1	20230928	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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PNP/PNP high power double bipolar transistor

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Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	3
	Thermal characteristics	
10	. Characteristics	6
11.	. Test information	9
	. Package outline	
	. Soldering	
	. Revision history	
	. Legal information	

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14 / 14

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